Dual 64-Bit Static Shift Register

The MC14517B dual 64-bit static shift register consists of two identical, independent, 64-bit registers. Each register has separate clock and write enable inputs, as well as outputs at bits 16, 32, 48, and 64. Data at the data input is entered by clocking, regardless of the state of the write enable input. An output is disabled (open circuited) when the write enable input is high. During this time, data appearing at the data input as well as the 16-bit, 32-bit, and 48-bit taps may be entered into the device by application of a clock pulse. This feature permits the register to be loaded with 64 bits in 16 clock periods, and also permits bus logic to be used. This device is useful in time delay circuits, temporary memory storage circuits, and other serial shift register applications.

Features

- Diode Protection on All Inputs
- Fully Static Operation
- Output Transitions Occur on the Rising Edge of the Clock Pulse
- Exceedingly Slow Input Transition Rates May Be Applied to the Clock Input
- 3-State Output at 64th-Bit Allows Use in Bus Logic Applications
- Shift Registers of any Length may be Fully Loaded with 16 Clock Pulses
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Pb-Free Packages are Available*

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Parameter	Symbol	Value	Unit
DC Supply Voltage Range	V_{DD}	-0.5 to +18.0	V
Input or Output Voltage Range (DC or Transient)	V _{in} , V _{out}	–0.5 to V _{DD} + 0.5	٧
Input or Output Current (DC or Transient) per Pin	I _{in} , I _{out}	±10	mA
Power Dissipation per Package (Note 1)	P _D	500	mW
Operating Temperature Range	T _A	-55 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Lead Temperature (8–Second Soldering)	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Temperature Derating: Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range V_{op} < (V_{in} or V_{op}) < V_{op}

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



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MARKING DIAGRAMS 16<u>ኩሉ ሉ ሉ ሉ ሉ ሉ</u> ሊ

MC14516BCP O AWLYYWWG 1 UUUUUU



SOIC-16 DW SUFFIX CASE 751G

PDIP-16

P SUFFIX

CASE 648

14517B AWLYYWWG O

A = Assembly Location WL, L = Wafer Lot

YY, Y = Year WW, W = Work Week G = Pb-Free Package

PIN ASSIGNMENT

Q16 _A [1 ●	16	V _{DD}
Q48 _A [2	15	Q16 _B
WE _A	3	14	Q48 _B
C _A	4	13	WE _B
Q64 _A	5	12	C _B
Q32 _A [6	11	Q64 _B
D _A [7	10	Q32 _B
V _{SS} [8	9	D _B

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14517BCP	PDIP-16	25 Units/Rail
MC14517BCPG	PDIP-16 (Pb-Free)	25 Units/Rail
MC14517BDW	SOIC-16	47/Rail
MC14517BDWG	SOIC-16 (Pb-Free)	47/Rail
MC14517BDWR2	SOIC-16	1000/Tape & Reel
MC14517BDWR2G	SOIC-16 (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

FUNCTIONAL TRUTH TABLE (X = Don't Care)

Clock	Write Enable	Data	16-Bit Tap	32-Bit Tap	48-Bit Tap	64-Bit Tap
0	0	Х	Content of 16-Bit Displayed	Content of 32–Bit Displayed	Content of 48-Bit Displayed	Content of 64–Bit Displayed
0	1	Х	High Impedance	High Impedance	High Impedance	High Impedance
1	0	Х	Content of 16-Bit Displayed	Content of 32-Bit Displayed	Content of 48-Bit Displayed	Content of 64–Bit Displayed
1	1	Х	High Impedance	High Impedance	High Impedance	High Impedance
	0	Data entered into 1st Bit	Content of 16-Bit Displayed	Content of 32–Bit Displayed	Content of 48-Bit Displayed	Content of 64–Bit Displayed
<i></i>	1	Data entered into 1st Bit	Data at tap entered into 17–Bit	Data at tap entered into 33–Bit	Data at tap entered into 49–Bit	High Impedance
~	0	Х	Content of 16-Bit Displayed	Content of 32–Bit Displayed	Content of 48-Bit Displayed	Content of 64-Bit Displayed
~	1	Х	High Impedance	High Impedance	High Impedance	High Impedance

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			- 5	5°C		25°C		125	5°C	
Characteristic	Symbol	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
Output Voltage "0" Level $V_{in} = V_{DD}$ or 0	V _{OL}	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
V_{in} = 0 or V_{DD} "1" Level	V _{OH}	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
Input Voltage "0" Level (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc)	V _{IL}	5.0 10 15	- <u>-</u> -	1.5 3.0 4.0	 _ _	- 2.25 4.50 6.75	1.5- 3.0 4.0	- - -	1.5 3.0 4.0	Vdc
"1" Level $(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	V _{IH}	5.0 10 15	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	Vdc
	ІОН	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	- - - -	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	- - - -	- 1.7 - 0.36 - 0.9 - 2.4	- - - -	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ Sink $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	I _{OL}	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mAdc
Input Current	I _{in}	15	-	± 0.1	_	±0.00001	± 0.1	-	± 1.0	μAdc
Input Capacitance (V _{in} = 0)	C _{in}	-	_	-	_	5.0	7.5	_	-	pF
Quiescent Current (Per Package)	I _{DD}	5.0 10 15	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μAdc
Total Supply Current (Note 3, 4) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching)	I _T	5.0 10 15			$I_T = (8)$	1.2 μΑ/kHz) f 3.8 μΑ/kHz) f 3.7 μΑ/kHz)	+ I _{DD}			μAdc
Three–State Leakage Current	I _{TL}	15	_	± 0.1	_	± 0.0001	± 0.1	_	± 3.0	μAdc

- Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.
 To calculate total supply current at loads other than 50 pF: I_T(C_L) = I_T(50 pF) + (C_L 50) Vfk where: I_T is in μA (per package), C_L in pF, V = (V_{DD} V_{SS}) in volts, f in kHz is input frequency, and k = 0.004.

SWITCHING CHARACTERISTICS (Note 5) (C $_L$ = 50 pF, T_A = $25\,^{\circ}C)$

Characteristic	Symbol	V _{DD}	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.65 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	tтын, tтны	5.0 10 15	- - -	100 50 40	200 100 80	ns
Propagation Delay Time t_{PLH} , t_{PHL} = (1.7 ns/pF) C_L + 390 ns t_{PLH} , t_{PHL} = (0.66 ns/pF) C_L + 177 ns t_{PLH} , t_{PHL} = (0.5 ns/pF) C_L + 115 ns	t _{РLН} , t _{РНL}	5.0 10 15	- - -	475 210 140	770 300 215	ns
Clock Pulse Width	t _{WH}	5.0 10 15	330 125 100	170 75 60	1 1 1	ns
Clock Pulse Frequency	f _{cl}	5.0 10 15	- - -	3.0 6.7 8.3	1.5 4.0 5.3	MHz
Clock Pulse Rise and Fall Time	t _{TLH} , t _{THL}	5.0 10 15		See (Note 7))	_
Data to Clock Setup Time	t _{su}	5.0 10 15	0 10 15	- 40 - 15 0	- - -	ns
Data to Clock Hold Time	t _h	5.0 10 15	150 75 35	75 25 10	- - -	ns
Write Enable to Clock Setup Time	t _{su}	5.0 10 15	400 200 110	170 65 50	- - -	ns
Write Enable to Clock Release Time	t _{rel}	5.0 10 15	380 180 100	160 55 40	1 1 1	ns

- The formulas given are for the typical characteristics only at 25°C.
 Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 When shift register sections are cascaded, the maximum rise and fall time of the clock input should be equal to or less than the rise and fall time of the data outputs, driving data inputs, plus the propagation delay of the output driving stage.

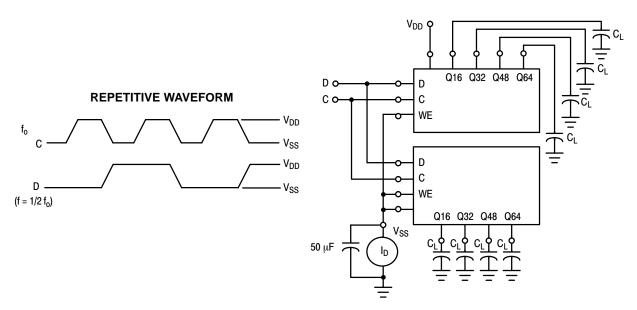
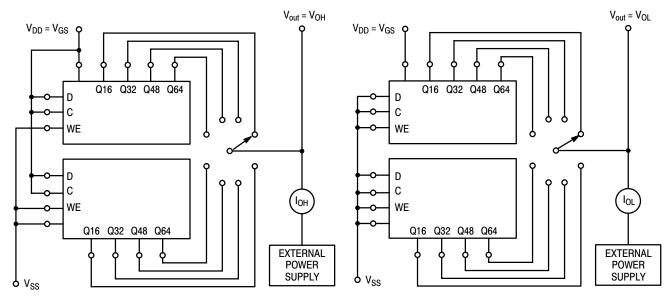


Figure 1. Power Dissipation Test Circuit and Waveform



(Output being tested should be in the high-logic state)

(Output being tested should be in the low-logic state)

Figure 2. Typical Output Source Current Characteristics Test Circuit

Figure 3. Typical Output Sink Current Characteristics Test Circuit

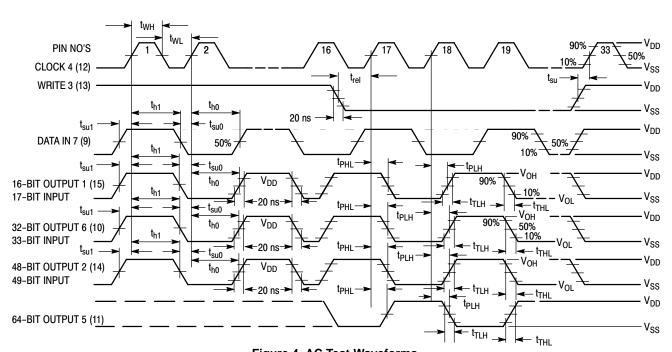
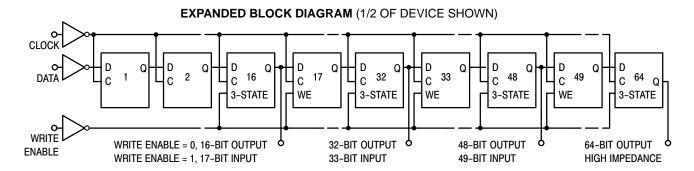
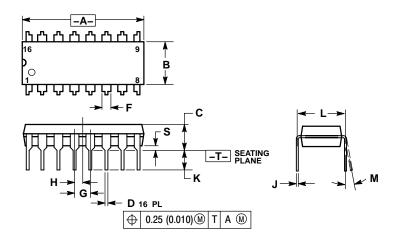


Figure 4. AC Test Waveforms



PACKAGE DIMENSIONS

PDIP-16 CASE 648-08 **ISSUE T**

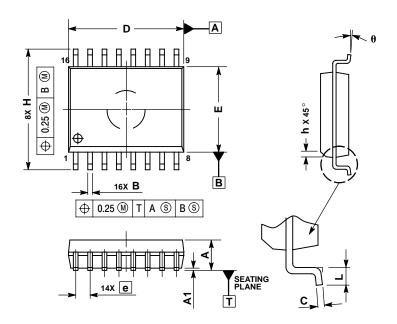


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD ELACH
- MOLD FLASH.

 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54 BSC	
Н	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
М	0°	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

SO-16 WB CASE 751G-03 **ISSUE C**



- NOTES:

 1. DIMENSIONS ARE IN MILLIMETERS.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR
- - PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION. SHALL BE 0.13 TOTAL IN
 EXCESS OF THE B DIMENSION AT MAXIMUM
 MATERIAL CONDITION.

	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
В	0.35	0.49			
С	0.23	0.32			
D	10.15	10.45			
E	7.40	7.60			
е	1.27	BSC			
Н	10.05	10.55			
h	0.25	0.75			
L	0.50	0.90			
q	0 °	7 °			

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